imall

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Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

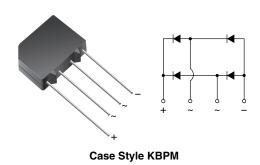


New Product

3KBP005M thru 3KBP08M

Vishay General Semiconductor

Glass Passivated Single-Phase Bridge Rectifier



SHA

PRIMARY CHARACTERISTICS						
I _{F(AV)}	3 A					
V _{RRM}	50 V to 800 V					
I _{FSM}	80 A					
I _R	5 μΑ					
V _F	1.05 V					
T _J max.	150 °C					

FEATURES

- UL recognition file number E54214
- · Ideal for printed circuit board
- · High surge current capability
- · High case dielectric strength
- Solder dip 260 °C, 40 s
- · Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

General purpose use in ac-to-dc bridge full wave rectification for switching power supply, home appliances, office equipment, and telecommunication applications.

MECHANICAL DATA

Case: KBPM Epoxy meets UL 94V-0 flammability rating Terminals: Silver plated leads, solderable per J-STD-002 and JESD22-B102 E4 suffix for consumer grade Polarity: As marked on body

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	3KBP 005M	3KBP 01M	3KBP 02M	3KBP 04M	3KBP 06M	3KBP 08M	UNIT
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	800	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	V
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	V
Maximum average forward output rectified current at $T_A = 55$ °C (Fig. 1)	I _{F(AV)}	3.0					А	
Peak forward surge current 50 Hz single half sine-wave superimposed on rated load	I _{FSM}	80					А	
Rating for fusing (t < 10 ms)	l ² t	l ² t 32					A ² s	
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150					°C	





3KBP005M thru 3KBP08M



Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)									
PARAMETER	TEST CONDITIONS	SYMBOL	3KBP 005M	3KBP 01M	3KBP 02M	3KBP 04M	3KBP 06M	3KBP 08M	UNIT
Maximum instantaneous forward voltage drop per diode	3.0 A	V _F	1.05					V	
Maximum DC reverse current at rated DC blocking voltage per diode	T _A = 25 °C T _A = 125 °C	I _R	5.0 500					μA	
Typical junction capacitance per diode	4.0 V, 1 MHz	CJ	25				pF		

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	3KBP 005M	3KBP 01M	3KBP 02M	3KBP 04M	3KBP 06M	3KBP 08M	UNIT
Typical thermal resistance ⁽¹⁾	$R_{ extsf{ heta}JA}\ R_{ extsf{ heta}JL}$	30 11				°C/W		

Note:

(1) Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with, 0.47 x 0.47" (12 x 12 mm) copper pads

ORDERING INFORMATION (Example)								
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE				
3KBP06M-E4/45	1.912	45	30	Tube				
3KBP06M-E4/51	1.912	51	600	Anti-static PVC tray				

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

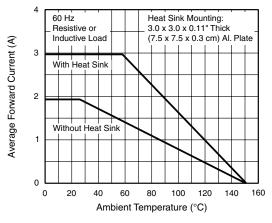
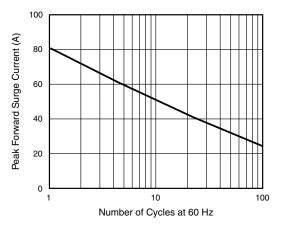
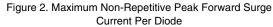


Figure 1. Forward Current Derating Curve







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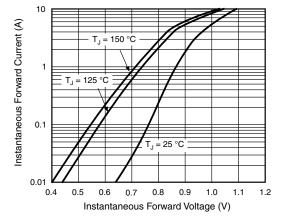


Figure 3. Typical Forward Characteristics Per Diode

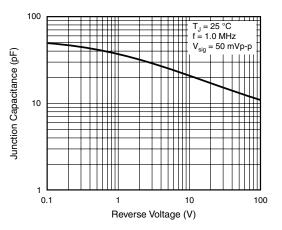


Figure 5. Typical Junction Capacitance Per Diode

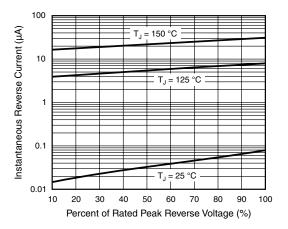
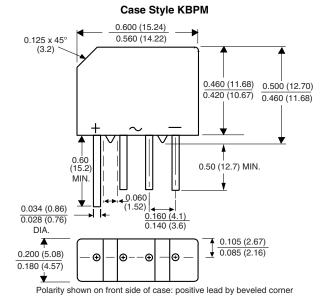


Figure 4. Typical Reverse Leakage Characteristics Per Diode





New Product



Vishay

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